3GPP TSG-RAN WG2 Meeting #113-e R2-210xxxx

**Online, January 25th – February 5th 2021**

**Agenda item: 5.4.3**

**Source: Samsung**

**Title: Summary of [011][NR15] UE Capabilites III (Samsung)**

**Document for: Discussion and Decision**

# 1 Brief scope of the contributions

This document contains the summary of documents from agenda item 5.4.3 (“xDD differentiation for SUL”, “Fallback per CC” and “Supported Number of TAG”) as per below excerpt from the session chair minutes:

* [AT113-e][011][NR15] UE Capabilites III (Samsung)

 Scope: Treat R2-2100016, R2-2100439, R2-2100440, R2-2101911, R2-2101912, R2-2101432, R2-2101430, R2-2101431, R2-2101660, R2-2101661, R2-2101354,

 Phase 1, determine agreeable parts, Phase 2, for agreeable parts Work on CRs.

 Intended outcome: Report and Agreed CRs.

 Deadline: Schedule A

xDD differentiation for SUL

Related to RP-202911, R2 is tasked to provide CRs.

Moved from 5.1:

[R2-2100016](file:///C%3A%5CUsers%5CDocs%5CR2-2100016.zip) Reply LS on UE capability xDD differentiation for SUL/SDL bands (R1-2009576; contact: Samsung) RAN1 LS in Rel-15 NR\_newRAT-Core To:RAN2 Cc:RAN4

[R2-2100439](file:///C%3A%5CUsers%5CDocs%5CR2-2100439.zip) xDD differentiation of UE capabilities for SUL/SDL bands Samsung CR Rel-15 38.306 15.12.0 0486 - F NR\_newRAT-Core

[R2-2100440](file:///C%3A%5CUsers%5CDocs%5CR2-2100440.zip) xDD differentiation of UE capabilities for SUL/SDL bands Samsung CR Rel-16 38.306 16.3.0 0487 - A NR\_newRAT-Core

[R2-2101911](file:///C%3A%5CUsers%5CDocs%5CR2-2101911.zip) Clarfication on FDD-TDD differentiation for SUL band Huawei, HiSilicon, Intel Corporation CR Rel-15 38.306 15.12.0 0522 - F NR\_newRAT-Core

[R2-2101912](file:///C%3A%5CUsers%5CDocs%5CR2-2101912.zip) Clarfication on FDD-TDD differentiation for SUL band Huawei, HiSilicon CR Rel-16 38.306 16.3.0 0523 - F NR\_newRAT-Core

[R2-2101432](file:///C%3A%5CUsers%5CDocs%5CR2-2101432.zip) Per UE capability differentiation for SUL bands Ericsson CR Rel-15 38.306 15.12.0 0508 - F NR\_newRAT-Core

**Fallback per CC**

Continue last meeting

[R2-2101430](file:///C%3A%5CUsers%5CDocs%5CR2-2101430.zip) Definition of Fallback per CC feature set Ericsson discussion

[R2-2101431](file:///C%3A%5CUsers%5CDocs%5CR2-2101431.zip) Definition of fallback per CC feature set Ericsson CR Rel-15 38.306 15.12.0 0507 - F NR\_newRAT-Core

[R2-2101660](file:///C%3A%5CUsers%5CDocs%5CR2-2101660.zip) Discussion on the definition of fallback per CC feature set Huawei, HiSilicon discussion Rel-15 NR\_newRAT-Core

[R2-2101661](file:///C%3A%5CUsers%5CDocs%5CR2-2101661.zip) CR to clarify the definition of fallback per CC feature set Huawei, HiSilicon CR Rel-15 38.306 15.12.0 0519 - F NR\_newRAT-Core

Supported Number of TAG

Continue last meeting

[R2-2101354](file:///C%3A%5CUsers%5CDocs%5CR2-2101354.zip) Clarification on the capability of supportedNumberTAG Apple discussion Rel-16 NR\_newRAT-Core, TEI16

# 2 Company comments to the contributions

## 2.1 xDD differentiation for SUL

This section deals with **DISC\_S1: xDD differentiation for SUL**.

According to the reply LS (R2-2100016) from RAN1, RAN1 provided the answers for the questions RAN2 requested on xDD differentiation for SUL/SDL bands.

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| “**Question 1:** Could per-UE capabilities for SUL/SDL bands be differentiated on the duplex mode(s) for Rel-15 and Rel-16?”Regarding Question 1 from RAN2, RAN1 concluded per-UE capabilities for SUL/SDL bands can be differentiated on the duplex mode(s) for Rel-15 and Rel-16.“**Question 2:** Which duplex mode(s) (i.e. FDD or TDD) for the per-UE capabilities which are differentiated by FDD and TDD are applied for SUL/SDL in both Rel-15 and Rel-16?”Regarding Question 2 from RAN2, RAN1 concluded Rel-16 per-UE capabilities with xDD differentiation and FRx differentiation can be differentiated for SUL/SDL bands by "per-band” capability signaling for each SUL band and SDL band. On the other hand, RAN1 didn’t make a conclusion on Rel-15 per-UE capability yet and will continue discussing it. |

However, RAN1 didn’t provide clear answers and the discussions had continued in the RAN plenary. In RAN#90-e meeting, following conclusion was made in RP-202911 i.e. how to apply the features can be xDD differentiated for SUL:

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| Conclusion:- No new signalling will be introduced in Rel-16 to provide a DL/UL configuration for an SUL carrier.- Per UE Capabilities that are FDD/TDD differentiated when applied to SUL carriers are indicated by the FDD capability (i.e. in effect the capabilities are not FDD/TDD differentiated for this case). Per UE capabilities that are TDD only are not applicable to SUL. RAN2 is tasked to prepare Rel-15 and 16 CRs to capture this agreement. |

***DISC S1\_1:*** *How to associate the SDL carriers to xDD?*

During the RAN plenary discussion, the conclusion only handles the association of the SDL carriers to FDD was made but how to associate the SDL carriers to xDD was not concluded. In this meeting, RAN1 is now discussing on this issue and the candidate option on the table would be:

1. Capability differentiation of SDL carriers is associated to the capabilities for TDD bands if SDL bands are overlapped with TDD bands, otherwise SDL bands can be associated to the FDD bands.
2. Capability differentiation of SDL carriers is always associated to the capabilities for FDD bands.

R2-2100439/R2-2100440 proposes the approach 1) above but other CRs are not touching this issues.

**Q1: How to associate the SDL carriers to xDD?**

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| **Company** | **Comments** |
| Qualcomm Incorporated | Wait for RAN1. We do not think it is technically correct to associate SDL to TDD purely from the basis of spectrum arrangement. There are many UE capabilities also related to baseband behaviours as well. |
| Huawei, HiSilicon | We need to wait for RAN1’s agreement. Technically we prefer 2). Perhaps it would also be good that in RAN1 discussion it can be confirmed whether the agreement would apply to both Rel-15 and Rel-16 per UE capabilities for SDL, as the current RAN1 discussion seems focusing on Rel-16 only. |
| OPPO (Qianxi) | Better to wait for RAN1 to conclude first. |

***DISC S1\_2:*** *How to capture the SUL differentiation in the specification?*

There are three types of CRs were submitted but the changes are based on what RAN plenary concluded in the above excerption. It is clear that RAN2 need to capture some description to clearly provide how the capability differentiation of SUL bands is achieved. There are two big approaches:

1. Option 1: Update the normative text procedure to describe conclusion of SUL/SDL differentiation.
* Huawei: R2-2101911/R2-2101911
* Ericsson: R2-2101432
1. Option 2: Add “Note” to describe the conclusion of SUL/SDL differentiation.
* Samsung: R2-2100439/R2-2100440

**Q2: How to capture the SUL/SDL differentiation in the specification? Companies provide the preferred way with further comments.**

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| **Company** | **Option?** | **Comments to the CR** |
| Qualcomm Incorporated |  | No strong view. |
| Huawei, HiSilicon | 1 | We prefer to add normative text instead of note as these are clarifications. |
| OPPO (Qianxi) | 2 | A note would be sufficient.As replied above, for SDL, we tend to wait for RAN1 conclusion first. |

**Conclusions (DISC\_S1): TBA**

## 2.2 **Fallback per CC**

This section deals with **DISC\_S2: Fallback per CC**.

In RAN#113-e, it was discussed the definition of fallback in case of feature sets per CC, but the changes related to this were postponed:

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| R2-2010539 Definition of fallback per CC feature set Ericsson CR Rel-15 38.306 15.11.0 0457 - F NR\_newRAT-Core- [011] Intermediate, Rapporteur: To continue discussing: whether there is any parameter in feature set per CC that may be unclear regarding the definition of fallback of feature set per CC (for both Rel-15 and Rel-16); how to capture any identified parameters into the definition of fallback of feature set per CC**[011] Postponed**R2-2010538 Definition of fallback per CC feature set Ericsson CR Rel-16 38.306 16.2.0 0456 - A NR\_newRAT-Core**[011] Postponed** |

In R2-2101430/R2-2101431, it is proposed that all the Rel-15 parameters present on Feature Set per CC level are applicable to the fallback concept defined in TS 38.306, except for SCS.

In R2-2101660/R2-2101661, it is proposed that Rel-15 fallback per CC feature set is a feature set per CC that has lower value than the reported values (i.e. MIMO layers and BW) while keeping the numerology(SCS) and modulation order the same.

All above contributions observed that the capabilities that are introduced in Rel-16 could be applicable to the fallback concept defined in 38.306. CRs suggest to re-word the definition of fallback per CC feature and fallback per band feature set.

* **Option 1**: Suggest to re-word the definition of fallback per CC feature and fallback per band feature set suggested in R2-3101431.

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| **Fallback per CC feature set:** A feature set per CC that has same or lower values than the values for the reported feature set per CC for a given carrier per band, while keeping the numerology. |

* **Option 2**: Suggest to re-word the definition of fallback per CC feature and fallback per band feature set suggested in R2-3101661.

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| **Fallback per band feature set:** A feature set per band that has lower capabilities than the reported capabilities from the reported feature set per band for a given band.**Fallback per CC feature set:** A feature set per CC that has lower capabilities of UE supported MIMO layers and BW while keeping the numerology and other parameters the same from the reported feature set per CC for a given carrier per band. |

Q3: Which CR is preferred if the changes are required?

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| **Company** | **Option?** | **Comments to the CR** |
| Qualcomm Incorporated | Option 2 | It is indeed true that lower capability does not necessary means lower value. We think though it is safer to keep the fallback which has the “same” capability to be included there, in order to avoid the UE indicating the same capability (though unlikely). |
| Huawei, HiSilicon | Option 2 | Proponent of R2-2101660/R2-2101661.Except for the clarification for Rel-15 spec, the IE which is ENUMERATED {supported} is introduced in Rel-16, we need to clarify how to understand the fallback for such capability. Besides, we understand the current wording “lower values” is not always accurate, as “lower values” does not always means “lower capability”. Thus, the re-wording on “lower values” is needed to avoid considering a better capability as the fallback capability. |
| OPPO (Zhongda) | See comment | The way in option1 seems more future proof but the wording “value” should be replaced with “capabilities” so we can have following change:**Fallback per band feature set:** A feature set per band that has same or lower capabilities than the reported capabilities from thereported feature set per band for a given band.**Fallback per CC feature set:** A feature set per CC that has same or lower capabilities than the capability of the reported feature set per CC for a given carrier perband. |

**Conclusions (DISC\_S2): TBA**

## 2.3 **Supported Number of TAG**

This section deals with **DISC\_S3: Supported Number of TAG**.

In last RAN2 meeting, the clarification of *supportedNumberTAG* capability was discussed, and companies wants to have more time to check further.



According to the description marked in yellow, it’s clear that for the BC with two band entries NW can configure the TAG per band entry. But for the BC with more than 2 band entries, especially for the mixed inter-/intra band BC, if UE indicates 2 TAGs, how to interpret the capability is not clear and needs to be clarified.

R2-2101354 explains that the current UE capability signalling will lead the NW misinterpretation on the UE capability when *supportedNumberTAG* < band entries in the BC, so the contribution proposes that the clarification is needed. Below options are suggested:

* **Option 1:** UE is required to support the different TAGs in the different bands if the TAG number < band entry number;

For the mix inter/intra-band BC:

* If UE reports the TAG number = band entry number, UE supports the different TAGs configured in both intra-band non-contiguous CA and inter-band CA;
* If UE reports TAG number < band entry number, UE only supports the different TAG configured in inter-band CA.
* **Option 2:** Introduce the association between the TAG and the band entries, e.g. via the cell grouping;

The cell grouping signaling designed for Async DC capability can be considered to be used to indicate the association between band entry and TAG.

Q4: Which option is preferred if the changes are required?

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| **Company** | **Option?** | **Comments to the CR** |
| Qualcomm Incorporated | Option 1 | We understand typical deployments can still be address with this solution. Option 2 is more flexible, but introduces complexity and overhead. |
| Huawei, HiSilicon | None  | We agree there may exist the case that supportedNumberTAG < band entries in the BC. In this case, it means different TAGs are on different band entries (some band entries may belong to the same TAG) according to the current spec. Option 1 is NBC change from NW perspective and Option 2 is too complicated. We don’t see any issue with current definition, and we prefer not to change the current specification. |
| OPPO (Qianxi) |  | We tend to see option-1 as the preferred starting point.On the other hand, option-1 may not be exhaustive so worth further clarification: e.g., * When the indicated TAG no. < the no. of band (for inter-band case only), whether the association between TAG and band can be arbitrary.
* When the indicated TAG no. > the no. of band (for inter-band case only) and the indicated TAG no. < the no. of band entry (considering intra-band non-contiguous case), whether the association between the extra TAG (= no. of TAG – no. of band) and the intra-band band-entries can be arbitrary.
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**Conclusions (DISC\_S3): TBA**

# 4 Conclusions

**Conclusions (DISC\_S1): TBA**

**Conclusions (DISC\_S2): TBA**

**Conclusions (DISC\_S3): TBA**